

Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer





PNP SILICON EPITAXIAL POWER TRANSISTOR

CSB1370 (9AW) TO-220

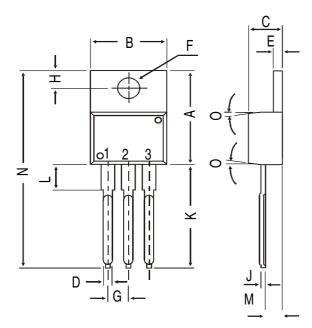
MARKING: AS BELOW

Designed For AF Power Amplifier.

ABSOLUTE MAXIMUM RATINGS	(Ta=25deg C)
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DESCRIPTION	SYMBOL		VALUE			UNIT
Collector -Base Voltage	VCBO		60			V
Collector -Emitter Voltage	VCEO		60			V
Emitter- Base Voltage	VEBO		5.0			V
Collector Current	IC		3.0			Å
Peak	ICP		6.0			Α
Power Dissipation @ Ta=25 deg C	PC		2.0			W
Power Dissipation @ Tc=25 deg C	. •		30			W
Junction Temperature	Tj		150			deg C
Storage Temperature Range	Tstg		-55 to +150			deg C
ELECTRICAL CHARACTERISTICS (Ta		ss Specified)	00 10 1 100			g c
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Voltage	VCEO	IC=1mA, IB=0	60	-	-	V
Collector Base Voltage	VCBO	IC=50uA, IE=0	60	-	-	V
Emitter Base Voltage	VEBO	IE=50uA,IC=0	5.0	-	-	V
Collector Cut off Current	ICBO	VCB=60V, IE=0	-	-	10	uA
Emitter Cut off Current	IEBO	VEB=4V,IC=0	-	-	10	uA
Collector Emitter Saturation Voltage	VCE(Sat)	IC=2A,IB=0.2A	-	-	1.5	V
Base Emitter Saturation Voltage	VBE(Sat)	IC=2A, IB=0.2A	-	-	1.5	V
DC Current Gain	hFE	IC=0.5A, VCE=5V	60	-	320	
Dynamic Characteristics						
Transition Frequency	ft	VCE=5V,IC=0.5A, f=5MHz	-	15	-	MHz
Collector Output Capacitance	Cob	VCB=10V, IE=0 f=1MHz	-	80	-	pF
hFE CLASSIFICATION:-	D: 60 -120;	E: 100 -200	F : 160 -320			
MARKING:	CSB 1370 D	CSB 1370 E	CSB 1370 F			

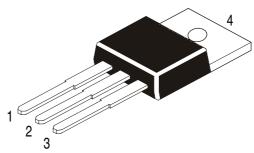
TO-220 Plastic Package



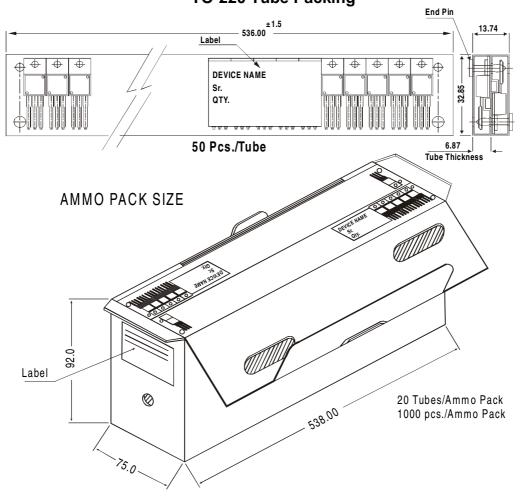
	DIM	MIN.	MAX.	
All diminsions in mm.	Α	14.42	16.51	
	В	9.63	10.67	
	C	3.56	4.83	
	D	_	0.90	
	Е	1.15	1.40	
	F	3.75	3.88	
	G	2.29	2.79	
	Τ	2.54	3.43	
	J	1	0.56	
	K	12.70	14.73	
	Ш	2.80	4.07	
	М	2.03	2.92	
	N		31.24	
₩ W	0	DEG 7		

PIN CONFIGURATION

- 1. BASE
- 2. COLLECTOR
- 3. EMITTER
- 4. COLLECTOR



TO-220 Tube Packing



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220 / FP	200 pcs/polybag 50 pcs/tube		3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"		17" x 15" x 13.5" 19" x 19" x 19"	16.0K 10.0K	36 kgs 29 kgs

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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